



2048MB Fully Buffered DIMM Server Memory Module

CM75FB2048-667

Key Features

- ◆ 240-pin, Fully Buffered dual in-line memory module (FB-DIMM)
- ◆ Ultra high density using 512 MBit SDRAM devices
- ◆ CRC and ECC error detection and correction
- ◆ Advanced Memory Buffer (AMB)
- ◆ 256 MB x 72
- ◆ JEDEC standard 1.5V high speed differential point-to-point link
- ◆ Four-bit prefetch architecture
- ◆ Off-chip driver (OCD) impedance calibration
- ◆ On-die termination (ODT)
- ◆ Low profile (1.2"), ideal for 1U rack mount servers

Selection Guide

CM75FB2048-667

MODULE SIZE:
2048 MByte

SPEED:
667: DDR2-667 (8.0 GB/s)



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General Description

The CM75FB2048 is a DDR2 Fully Buffered Dual Inline Memory Module (FB-DIMM), designed for applications in which both performance and density are critical. This DIMM includes Error Checking and Correcting (ECC) for maximum reliability, and has an Advanced Memory Buffer (AMB) for data, address and control signals to enable fully configured systems. These modules are constructed using 512 MBit SDRAMs, and are fully compliant with JEDEC specifications.

These DIMMs are constructed using 128MB x 4 SDRAMs in BGA packages. The module also includes an EEPROM to support Serial Presence Detect (SPD) requirements. Decoupling capacitors are mounted on the printed circuit board for each SDRAM device, and On-Die Termination is provided on all lines. The synchronous design of these Corsair SDRAM DIMMs allows precise cycle control with the use of the system clock. I/O transactions are possible on every clock cycle. The high clock frequency and high density of this device enable a high level of performance to be achieved in advanced workstations and servers.



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Pin Assignment

Pin	Front	Pin	Front	Pin	Front	Pin	Back	Pin	Back	Pin	Back
1	VDD	41	/PN13	81	VSS	121	VDD	161	/SN13	201	VSS
2	VDD	42	VSS	82	PS4	122	VDD	162	VSS	202	SS4
3	VDD	43	VSS	83	/PS4	123	VDD	163	VSS	203	/SS4
4	VSS	44	RFU	84	VSS	124	VSS	164	RFU1	204	VSS
5	VDD	45	RFU	85	VSS	125	VDD	165	RFU1	205	VSS
6	VDD	46	VSS	86	RFU1	126	VDD	166	VSS	206	RFU1
7	VDD	47	VSS	87	RFU1	127	VDD	167	VSS	207	RFU1
8	VSS	48	PN12	88	VSS	128	VSS	168	SN12	208	VSS
9	VCC	49	/PN12	89	VSS	129	VCC	169	/SN12	209	VSS
10	VCC	50	VSS	90	PS9	130	VCC	170	VSS	210	SS9
11	VSS	51	PN6	91	/PS9	131	VSS	171	SN6	211	/SS9
12	VCC	52	/PN6	92	VSS	132	VCC	172	/SN6	212	VSS
13	VCC	53	VSS	93	PS5	133	VCC	173	VSS	213	SS5
14	VSS	54	PN7	94	/PS5	134	VSS	174	SN7	214	/SS5
15	VTT	55	/PN7	95	VSS	135	VTT	175	/SN7	215	VSS
16	VID1	56	VSS	96	PS6	136	VID0	176	VSS	216	SS6
17	/RESET	57	PN8	97	/PS6	137	DNU/M_TEST	177	SN8	217	/SS6
18	VSS	58	/PN8	98	VSS	138	VSS	178	/SN8	218	VSS
19	RFU2	59	VSS	99	PS7	139	RFU2	179	VSS	219	SS7
20	RFU2	60	PN9	100	/PS7	140	RFU2	180	SN9	220	/SS7
21	VSS	61	/PN9	101	VSS	141	VSS	181	/SN9	221	VSS
22	PN0	62	VSS	102	PS8	142	SN0	182	VSS	222	SS8
23	/PN0	63	PN10	103	/PS8	143	/SN0	183	SN10	223	/SS8
24	VSS	64	/PN10	104	VSS	144	VSS	184	/SN10	224	VSS
25	PN1	65	VSS	105	RFU2	145	SN1	185	VSS	225	RFU2
26	/PN1	66	PN11	106	RFU2	146	/SN1	186	/SN11	226	RFU2
27	VSS	67	/PN11	107	VSS	147	VSS	187	/SN11	227	VSS
28	PN2	68	VSS	108	VDD	148	SN2	188	VSS	228	SCK
29	/PN2	69	VSS	109	VDD	149	/SN2	189	VSS	229	/SCK
30	VSS	70	PS0	110	VSS	150	VSS	190	SS0	230	VSS
31	PN3	71	/PS0	111	VDD	151	SN3	191	/SS0	231	VDD
32	/PN3	72	VSS	112	VDD	152	/SN3	192	VSS	232	VDD
33	VSS	73	PS1	113	VDD	153	VSS	193	SS1	233	VDD
34	PN4	74	/PS1	114	VSS	154	SN4	194	/SS1	234	VSS
35	/PN4	75	VSS	115	VDD	155	/SN4	195	VSS	235	VDD
36	VSS	76	PS2	116	VDD	156	VSS	196	SS2	236	VDD
37	PN5	77	/PS2	117	VTT	157	SN5	197	/SS2	237	VTT
38	/PN5	78	VSS	118	SA2	158	/SN5	198	VSS	238	VDDSPD
39	VSS	79	PS3	119	SDA	159	VSS	199	SS3	239	SA0
40	PN13	80	/PS3	120	SCL	160	SN13	200	/SS3	240	SA1



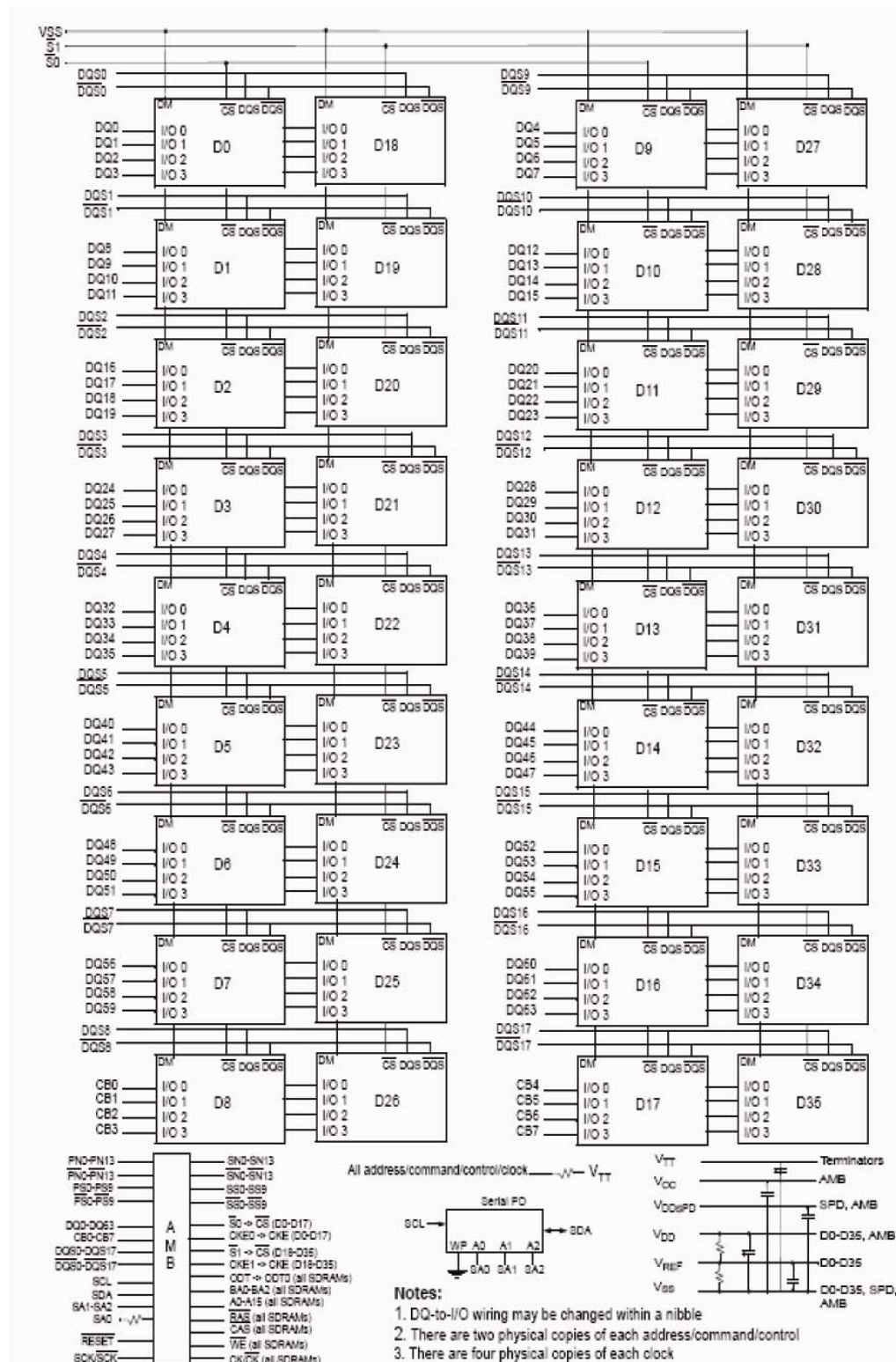
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Pin Description

Pin Name	Pin Description	Count	Note
SCK	System Clock Input, positive line	1	1
/SCK	System Clock Input, negative line	1	1
PN[13:0]	Primary Northbound Data, positive lines	14	
/PN[13:0]	Primary Northbound Data, negative lines	14	
PS[9:0]	Primary Southbound Data, positive lines	10	
/PS[9:0]	Primary Southbound Data, negative lines	10	
SN[13:0]	Secondary Northbound Data, positive lines	14	
/SN[13:0]	Secondary Northbound Data, negative lines	14	
SS[9:0]	Secondary Southbound Data, positive lines	10	
/SS[9:0]	Secondary Southbound Data, negative lines	10	
SCL	Serial Presence Detect (SPD) Clock Input	1	
SDA	SPD Data Input / Output	1	
SA[2:0]	SPD Address Inputs, also used to select the DIMM number in the AMB	3	
VID[1:0]	Voltage ID: These pins must be unconnected for DDR2-based Fully Buffered DIMMs VID[0] is VDD value: OPEN = 1.8 V, GND = 1.5 V; VID[1] is VCC value: OPEN = 1.5 V, GND = 1.2 V	2	
/RESET	AMB reset signal	1	
RFU	Reserved for Future Use	16	2
VCC	AMB Core Power and AMB Channel Interface Power (1.5 Volt)	8	
VDD	DRAM Power and AMB DRAM I/O Power (1.8 Volt)	24	
VTT	DRAM Address/Command/Clock Termination Power (VDD/2)	4	
VDDSPD	SPD Power	1	
VSS	Ground	80	
DNU/M_Test	The DNU/M_Test pin provides an external connection on R/Cs A-D for testing the margin of Vref which is produced by a voltage divider on the module. It is not intended to be used in normal system operation and must not be connected (DNU) in a system. This test pin may have other features on future card designs and if it does, will be included in this specification at that time.	1	1
	Total	240	

Note: <1> System Clock Signals SCK and SCK switch at one half the DRAM CK/CK frequency.
 <2> Eight pins reserved for forwarded clocks, eight pins reserved for future architecture flexibility.

Block Diagram





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DC Electrical Specifications

Absolute Maximum DC Ratings

SYMBOL	PARAMETER		MIN	MAX	UNITS
VDD	VDD Supply Voltage Relative to VSS		-0.5	2.3	V
VTT	VTT Supply Voltage Relative to VSS		-0.5	2.3	V
VCC	VDDL Supply Voltage Relative to VSS		-0.3	1.75	V
VIN, VOUT	Voltage on any Pin Relative to VSS		-0.3	1.75	V
TSTG	Storage Temperature (Tcase)		-55	100	C
TOPR	Operating Temperature DRAM (Tcase)*		0	95	C
IL	Leakage Current	Link	-5	5	μA
		Reset	-90	90	μA
TOPR	Operating Temperature AMB (Tcase)		0	110	C

Recommended DC Operative Conditions

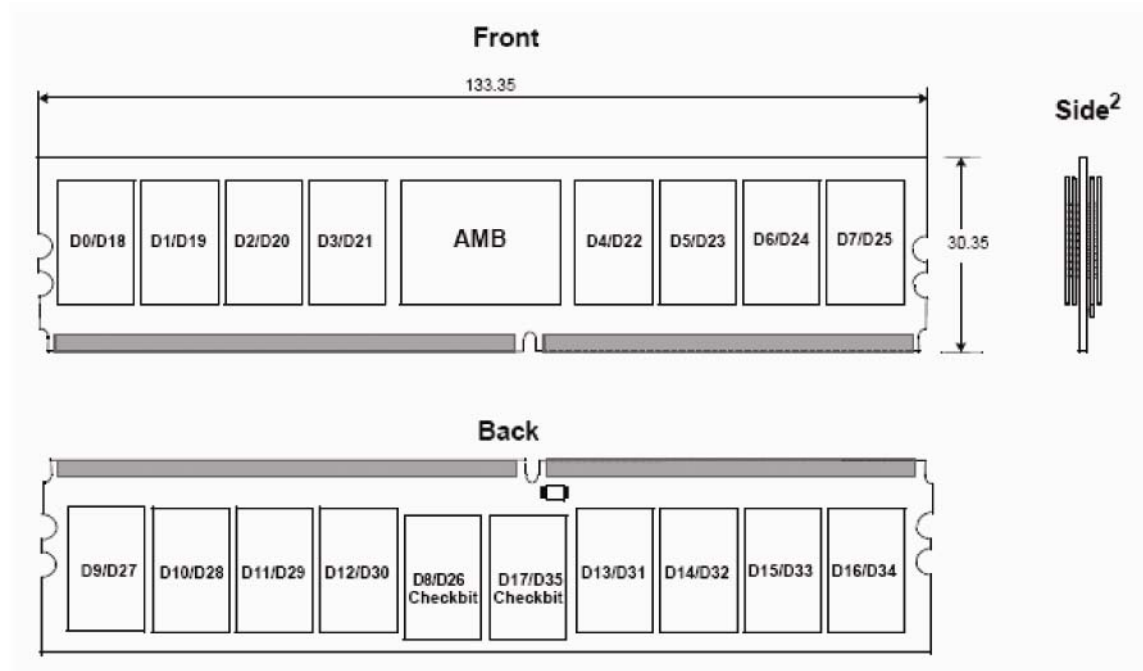
SYMBOL	PARAMETER	MIN	NOM	MAX	UNITS
VDD	Supply Voltage	1.7	1.8	1.9	V
VCC	AMB Supply Voltage	1.46	1.50	1.54	V
VTT	I/O Termination Voltage (system)	0.48x VDD	0.50 x VDD	0.52 x VDD	V

DC Electrical Characteristics

SYMBOL	PARAMETER	MIN	MAX	UNITS
VDDSPD	Supply Voltage	3.0	3.6	V
VIH	Input High Voltage: Logic 1; SPD	2.1	VDDSPD	V
VIL	Input Low Voltage: Logic 0; SPD		0.8	V
VOL	Output Low Voltage: IO _{UT} = 3mA	-	0.4	V

For DRAM case temperature above 85 C, the Auto-Refresh Command interval must be reduced to 3.9us.

Package Information



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